Anomalous Hall effect in type-I Weyl metals beyond the noncrossing approximation

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We study the anomalous Hall effect (AHE) in tilted Weyl metals with Gaussian disorder due to the crossed X and Ψ diagrams in this work. The importance of such diagrams to the AHE has been demonstrated recently in two-dimensional (2D) massive Dirac model and Rashba ferromagnets. It has been shown that the inclusion of such diagrams dramatically changes the total AHE in such systems. In this work, we show that the contributions from the X and Ψ diagrams to the AHE in tilted Weyl metals are of the same order of the noncrossing diagram we studied in a previous work, but with the opposite sign. The total contribution of the X and Ψ diagrams cancels the majority of the contribution from the noncrossing diagram in tilted Weyl metals, similar to the 2D massive Dirac model. We also discuss the difference of the contributions from the crossed diagrams between the 2D massive Dirac model and the tilted Weyl metals. At last, we discuss the experimental relevance of observing the AHE due to the X and Ψ diagrams in type-I Weyl metal Co₃Sn₂S₂.

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I. INTRODUCTION

The anomalous Hall effect (AHE) has been a topic of interest since it was first observed in ferromagnetic iron by Edwin Hall in 1881 [1]. It is analogous to a usual Hall effect but without the need of an external magnetic field [2,3]. The transverse motion in the anomalous Hall systems originates from the spin-orbit interaction, and to have a net transverse current, the time reversal symmetry (TRS) has to be broken in the system [2-6]. In insulators or semiconductors, the anomalous Hall conductivity is quantized and insensitive to impurity scatterings. In metals, however, the impurity scatterings affect the AHE significantly, and the AHE in such cases can be divided into the intrinsic contribution, which is due to the nontrivial topology of the electronic band structure and remains in the clean limit, and the extrinsic contribution, which is due to the impurity scatterings [5]. The anomalous Hall current can be obtained either from the quantum Kubo-Streda (OKS) formula [7] or from a semiclassical Boltzmann equation (SBE) approach [4,5]. The former approach is more systematic whereas the latter is physically more transparent.

The extrinsic AHE depends on the type of impurities in general. For simplicity, we focus on the Gaussian white noise disorder in this work. It has been well known that the Feynman diagrams with crossed impurity lines shown in Figs. 1(b)–1(d) result in a longitudinal conductivity which is smaller than the noncrossing diagram by a factor of $1/\epsilon_F \tau$ due to the restricted phase space of two rare impurity scatterings, so the crossed diagrams are usually neglected in computing the longitudinal conductivity. For a long time, the crossed diagrams were also ignored for the AHE and only the Feynman diagrams with noncrossing impurity scattering lines were considered for the

AHE [4,5,8]. However, for the AHE, both the noncrossing and crossed diagrams contain the rare impurity processes [9,10] and are suppressed by $1/k_F l \ll 1$ compared to the longitudinal conductivity for weak impurity systems. The two types of diagrams may then contribute the same order of magnitude to the AHE as was demonstrated in recent years in two-dimensional (2D) Rashba ferromagnets and the 2D massive Dirac model [9,11,12].

The account of the crossed diagrams in a number of anomalous Hall systems changes the total AHE in the systems dramatically [9–12]. For example, the inclusion of the X and Ψ diagrams in Figs. 1(b)–1(d) in 2D Rashba ferromagnetic metal results in a nonvanishing AHE instead of the vanishing result under the noncrossing approximation (NCA) [9,13,14]. In the 2D massive Dirac model, the X and Ψ diagrams almost cancel out the NCA contribution at high energy [11,12]. It was also shown that the same crossed diagrams play an important role for the AHE on the surface of a topological Kondo insulator [10], for the Kerr effect in chiral *p*-wave superconductors [15], and for the extrinsic spin Hall effect across the weak and strong scattering regimes [16,17].

The above cases show that the crossed diagrams play an important role for a more complete study of the AHE in a general case. For that reason, we study the contributions of the crossed diagrams, namely, the X and Ψ diagrams to the AHE in three-dimensional (3D) tilted Weyl metals with breaking TRS [18,19] and weak Gaussian disorder in this work. Although the SBE approach can yield the same result for the AHE as the QKS formula for the noncrossing diagram in isotropic systems [5], it is not convenient for calculating the AHE from the X and Ψ diagrams because it is very difficult to compute the scattering rates for such diagrams. We then employ the QKS formula and the diagrammatic technique to study the X and Ψ diagrams in tilted Weyl metals in this work.

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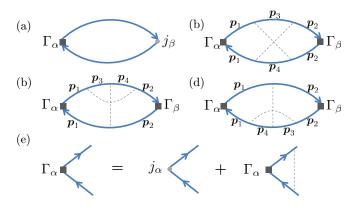


FIG. 1. (a) The Feynman diagram of the response function $\Pi^{I}_{\alpha\beta}$ under the noncrossing approximation (NCA) in the spin basis. The thick solid lines are Green's function in the spin basis under the Born approximation, and the solid square represents the current vertex Γ_{α} renormalized by the ladder diagram under the NCA. (b) The X diagram with two crossed impurity lines. (c and d) The Ψ diagram with two crossed impurity lines. (e) The recursion equation satisfied by the renormalized current vertex Γ_{α} .

Diagrams with more crossed impurity lines have a smaller contribution in $1/\epsilon_F \tau$ for Gaussian disorder.

For untilted Weyl metals it has been shown that the impurity scatterings have little effect on the AHE only if the Fermi energy is not very far from the Weyl nodes [20]. This is because the low-energy effective Hamiltonian of a single Weyl node of the untilted Weyl metal gains an emergent TRS and the AHE due to the impurity scatterings vanishes. For tilted Weyl metals, the tilting breaks the TRS of the effective Hamiltonian of a single Weyl node [21,22] and the impurity scatterings have significant effects on the AHE in such a system [23,24]. In a previous paper [24], we have studied the disorder-induced AHE in tilted Weyl metals due to the noncrossing diagrams and obtained both the intrinsic and extrinsic contribution for such diagrams from the quantum Kubo-Streda formula. We also separated the two different extrinsic contributions, namely, the side jump and skew scattering contribution from the noncrossing diagrams in this system. The study of the crossed diagrams for the tilted Weyl metals in this work is an important supplement of the skew scattering contribution to the AHE in such a system.

The skew scattering contribution to the AHE comes from the diffractive scattering of electrons off two impurities, as can be seen from the crossed X and Ψ diagrams [10], as well as the noncrossing skew scattering diagrams in Ref. [5]. For the two scattering processes to interfere, the two impurities need to be close enough for Gaussian disorder, i.e., with a distance of the order of the Fermi wavelength. This is verified by the calculation of the AHE from the X and Ψ diagrams in the real space [9,10].

We show that the contribution from both the X and Ψ diagrams for tilted Weyl metals with Gaussian disorder is of the same order of the contribution from the NCA diagram we studied in the previous work [24], i.e., $\sim \tau^0$. This is different from the 2D massive Dirac model for which the contribution from the Ψ diagram vanishes for Gaussian disorder [11,12]. On the other hand, our calculation shows that the total con-

tribution of the X and Ψ diagram cancels a majority of the contribution from the NCA diagram for tilted Weyl metals. This is similar to the 2D massive Dirac model. However, the inclusion of the X and Ψ diagram does not change the dependence of the anomalous Hall conductivity on the Fermi energy whereas in 2D massive Dirac model, the crossed diagram changes the total anomalous Hall conductivity from $\sigma_{xy} \sim m/\epsilon_F$ for the NCA diagram to $\sigma_{xy} \sim (m/\epsilon_F)^3$ [12].

We also discussed the experimental relevance of observing the effects of the X and Ψ diagrams in tilted Weyl metals, such as $Co_3Sn_2S_2$ [25–27]. We point out that the density of the Gaussian disorder needed to observe the contributions of the crossed X and Ψ diagrams is much higher than that of observing the noncrossing diagram with single impurity scatterings, such as the side jump contribution, since the former corresponds to electron scatterings by pairs of closely located impurities with a distance of the order of the Fermi wavelength. We estimated that the impurity density needed to observe the AHE due to the X and Ψ diagrams is $n_{imp}^{sk} >$ $\sqrt{2}/(\lambda_F l_{\phi})^{3/2}$ for 3D tilted Weyl metals, where l_{ϕ} is the phase coherence length and λ_F is the Fermi wavelength and $l_{\phi} \gg \lambda_F$ (see the Discussion section). As a comparison, the impurity density needed to observe the AHE from the noncrossing diagram with single impurity scatterings is $n_{imp}^{sj} > 1/(l_{\phi})^3$, which is much lower than n_{imp}^{sk} . Another issue is that the intrinsic AHE from the Chern-Simons term is much higher than the AHE from both the noncrossing and crossed diagrams in Co₃Sn₂S₂ with Gaussian disorder, so the effects of the Gaussian disorder on the AHE is not very distinguishable in experiments in this system. We propose that one can observe the effects of the Gaussian disorder on the AHE by measuring the anomalous Nernst effect (ANE) in such a system because the Chern-Simons term has no contribution to the ANE and the contributions of the Gaussian disorder to the ANE and AHE are proportional to each other.

This paper is organized as follows. In Sec. II, we present the model and the calculation of the anomalous Hall effect due to the crossed X and Ψ diagrams in tilted Weyl metals, and compare the AHE from the crossed diagrams with the noncrossing diagram, as well as with other systems, such as the 2D massive Dirac model. In Sec. III, we have a discussion of the experimental relevance of observing the effects of X and Ψ diagrams. In Sec. IV, we have a summary of this work.

II. AHE IN TILTED WEYL METALS DUE TO X AND Ψ DIAGRAMS

The low-energy physics of a type-I Weyl metal with breaking TRS can be described by an effective low-energy Hamiltonian of two independent Weyl nodes and a topological Chern-Simons term [24,28]. The Chern-Simons term results in an AHE proportional to the distance of the two Weyl nodes and is not affected by the impurity scatterings. We will then focus on the low-energy effective Hamiltonian of the Weyl nodes in the following, which is

$$H = \sum_{\chi} (\chi v \boldsymbol{\sigma} \cdot \mathbf{p} + \mathbf{u}_{\chi} \cdot \mathbf{p}), \qquad (1)$$

where $\chi = \pm 1$ is the chirality of the two Weyl nodes, σ are the Pauli matrices, and \mathbf{u}_{χ} is a tilting velocity with $u_{\chi} < v$ for type-I Weyl metals we consider in this work. Here we assume the tilting $\mathbf{u}_{+} = -\mathbf{u}_{-} = \mathbf{u}$, i.e., the tilting is opposite for the two valleys. For this case, the AHE in the two Weyl nodes adds up instead of cancel out. The Hamiltonian H_{χ} for each single valley results in two tilting linear bands $\epsilon_{\pm} = \pm vp + \mathbf{u}_{\chi} \cdot \mathbf{p}$. The tilting term breaks the TRS of a single Weyl node so the AHE from each valley does not vanish. The term $\chi v\sigma \cdot \mathbf{p}$ breaks the global TRS so the total AHE of the two valleys is nonzero.

We consider weak Gaussian disorder (white noise) with random potential $V(\mathbf{r}) = V_0 \sum_a \delta(\mathbf{r} - r_a)$ and correlation $\langle V(\mathbf{r})V(\mathbf{r}') \rangle = \gamma \delta(\mathbf{r} - \mathbf{r}')$, where $\gamma = n_{imp}V_0^2$ and n_{imp} is the impurity density. We assume that all the higher-order correlators of the impurity potential vanish for simplicity, and the mean free path of the electrons is much larger than the Fermi wavelength, i.e., $k_F l \gg 1$ or $\epsilon_F \tau \gg 1$. The anomalous Hall conductivity may be written in two parts, σ_H^{I} and σ_H^{II} , in the Kubo-Streda formula [5,7]. Formally, σ_H^{I} takes into account the contribution on the Fermi surface, and σ_{H}^{II} includes the contribution from the whole Fermi sea. Since σ_{H}^{II} is not sensitive to impurity scatterings and its contribution in the clean limit has been studied in previous works for tilted Weyl metals [21,22], we only need to study the σ_H^{I} part in this work. The leading order contribution to the response function $\Pi^{\mathbf{I}}_{\alpha\beta}$ includes the diagrams in Fig. 1, where Fig. 1(a) is the diagram under the NCA and has been studied in our previous work [24]. The NCA diagram includes both the intrinsic and extrinsic contributions, and both contributions to the AHE are independent of the scattering rate $1/\tau$ in the leading order, i.e., $\sim \tau^0$. For the crossed diagrams in Figs. 1(b)–1(d), previous works [9,10,12] have shown that for Gaussian disorder, the leading order AHE from these diagrams for 2D Rashba ferromagnets and massive Dirac models is of the same order as the noncrossing diagram in Fig. 1(a), i.e., $\sim \tau^0$. In the following, we study the contribution of the crossed X and Ψ diagrams for tilted Wevl metals and compare the leading order contribution of these diagrams with the noncrossing diagram in Fig. 1(a). Diagrams with more crossed impurity lines have a smaller contribution in $1/\tau$ and so are negligible.

We assume that the impurity potential is diagonal for both the spin and valley index, so the two valleys decouple and one can compute the AHE in each valley separately. The leading order contribution to the AHE from the NCA diagram of the tilted Weyl metals has been worked out in our previous work [24]. The total dc anomalous Hall conductivity from the noncrossing diagram for the two Weyl nodes is $\sigma_{xy}^{NCA} = 4e^2 \epsilon_F u/3\pi^2 v^2$ in the leading order of u/v for **u** in the *z* direction. As a comparison, we compute the anomalous Hall conductivity in the dc limit due to the crossed *X* and Ψ diagram in the tilted Weyl metals in the leading order of u/vin the following.

We consider a uniform electric field $\mathbf{E} = -\partial_t \mathbf{A}$ applied to the system. In the linear response regime $j_{\alpha}^{\mathbf{I}} = \Pi_{\alpha\beta}^{\mathbf{I}} A^{\beta}$, where $A^{\alpha} = (0, \mathbf{A})$. The response functions $\Pi_{\alpha\beta}^{\mathbf{I}}$ in the dc limit for the X and Ψ diagrams for a single Weyl node (e.g., $\chi = 1$) are, respectively,

$$\Pi_{\alpha\beta}^{X} = \gamma^{2}\omega \sum_{\mathbf{p}_{1},...,\mathbf{p}_{4}} \int \frac{d\epsilon}{2\pi i} \frac{dn_{F}(\epsilon)}{d\epsilon} \delta(\mathbf{p}_{1} + \mathbf{p}_{2} - \mathbf{p}_{3} - \mathbf{p}_{4})$$

$$\times \operatorname{Tr}[\Gamma_{\alpha} \mathbf{G}^{\mathrm{R}}(\mathbf{p}_{1})\mathbf{G}^{\mathrm{R}}(\mathbf{p}_{3})\mathbf{G}^{\mathrm{R}}(\mathbf{p}_{2})\Gamma_{\beta}\mathbf{G}^{\mathrm{A}}(\mathbf{p}_{2})$$

$$\times G^{A}(\mathbf{p}_{4})G^{A}(\mathbf{p}_{1})] \qquad (2)$$

and

$$\Pi^{\Psi}_{\alpha\beta} = \gamma^{2}\omega \sum_{\mathbf{p}_{1},\dots,\mathbf{p}_{4}} \int \frac{d\epsilon}{2\pi i} \frac{dn_{F}(\epsilon)}{d\epsilon} \delta(\mathbf{p}_{1} + \mathbf{p}_{4} - \mathbf{p}_{2} - \mathbf{p}_{3})$$

$$\times \operatorname{Tr}[G^{A}(\mathbf{p}_{1})\Gamma_{\alpha}G^{R}(\mathbf{p}_{1})G^{R}(\mathbf{p}_{3})G^{R}(\mathbf{p}_{4})$$

$$\times G^{R}(\mathbf{p}_{2})\Gamma_{\beta}G^{A}(\mathbf{p}_{2}) + G^{A}(\mathbf{p}_{1})\Gamma_{\alpha}G^{R}(\mathbf{p}_{1})$$

$$\times G^{R}(\mathbf{p}_{2})\Gamma_{\beta}G^{A}(\mathbf{p}_{2})G^{A}(\mathbf{p}_{4})G^{A}(\mathbf{p}_{3})], \qquad (3)$$

where $G^{R/A}$ is the retarded or advanced Green's function (GF) of the tilted Weyl metals, and Γ_{α} is the current vertex renormalized by the noncrossing ladder diagram [24]. We have omitted the argument ϵ in $G^{R/A}(\epsilon, \mathbf{p})$ in the above equations for brevity.

The impurity averaged retarded or advanced GF in a single valley (e.g., with $\chi = 1$) under the first Born approximation is [24]

$$G^{R/A}(\epsilon, \mathbf{p}) = (\epsilon - v\boldsymbol{\sigma} \cdot \mathbf{p} - \mathbf{u} \cdot \mathbf{p} - \boldsymbol{\Sigma}^{R/A})^{-1}, \qquad (4)$$

where the self-energy due to the impurity scatterings is $\Sigma^{R/A} = \gamma \sum_{\mathbf{p}} G_0^{R/A}(\mathbf{p}) = \mp \frac{i}{2\tau} [1 + \mathbf{\Delta}(\mathbf{u}) \cdot \boldsymbol{\sigma}]$ with $1/\tau = \pi \gamma g(\epsilon_F)$, $g(\epsilon_F) = \int \frac{d^3p}{(2\pi)^3} \delta(\mathbf{u} \cdot \mathbf{p} + vp - \epsilon_F) = \frac{\epsilon_F^2 v}{2\pi^2 (v^2 - u^2)^2}$ being the density of states at the Fermi energy $\epsilon_F > 0$ and $\mathbf{\Delta}(\mathbf{u}) = -\mathbf{u}/v$. We note here that the self-energy under the self-consistent Born approximation produces the same AHE as that under the first Born approximation in the leading order of $\epsilon_F \tau$ for the Gaussian disorder. The inclusion of diagrams with crossed impurity lines in the self-energy also only results in corrections to the AHE in the higher orders of $1/\epsilon_F \tau$.

For the calculation in this work, it is convenient to write the $G^{R/A}$ in Eq. (4) as

$$G^{R/A}(\epsilon, \mathbf{p}) = \frac{\left(\epsilon \pm \frac{i}{2\tau} - \boldsymbol{u} \cdot \boldsymbol{p}\right)\sigma^{0} + v\boldsymbol{p} \cdot \boldsymbol{\sigma} \mp \frac{i}{2\tau}(\boldsymbol{\Delta} \cdot \boldsymbol{\sigma})}{\left(\epsilon - \epsilon_{p}^{+} \pm \frac{i}{2\tau^{+}}\right)\left(\epsilon - \epsilon_{p}^{-} \pm \frac{i}{2\tau^{-}}\right)}, \quad (5)$$

with $1/\tau^{\pm} = \frac{1}{\tau} (1 \pm \frac{\mathbf{p} \cdot \mathbf{\Delta}}{p}).$

The renormalized current vertex Γ_{α} in Eqs. (2) and (3) has been worked out in our previous work [24]. The bare current vertex for the tilted Weyl metals is $\hat{j}_{\alpha} = e(v\sigma_{\alpha} + u_{\alpha}\sigma_{0})$ (we define $u_{0} \equiv 0$). By expressing \hat{j}_{α} and Γ_{α} with the Pauli matrices as $\hat{j}_{\alpha} = \mathcal{J}_{\alpha\beta}\sigma_{\beta}$ and $\hat{\Gamma}_{\alpha} = \Gamma_{\alpha\beta}\sigma_{\beta}, \alpha, \beta = 0, x, y, z$, one can solve the coefficients of the renormalized current vertex as $\Gamma_{\alpha\beta} = \mathcal{J}_{\alpha\gamma}\mathcal{D}_{\gamma\beta}$, where the summation over the repeated index γ is implied as usual and $\mathcal{D} = (1 - \gamma \mathcal{I})^{-1}$ is the 4 × 4 diffusion matrix with the polarization operator \mathcal{I} defined as

$$\mathcal{I}_{\alpha\beta} = \frac{1}{2} \int \frac{d\mathbf{p}}{(2\pi)^3} \text{Tr}[\sigma_{\alpha} \mathbf{G}^{\mathbf{R}}(\boldsymbol{\epsilon} + \boldsymbol{\omega}, \mathbf{p} + \mathbf{q})\sigma_{\beta} \mathbf{G}^{\mathbf{A}}(\boldsymbol{\epsilon}, \mathbf{p})].$$
(6)

In our previous work [24], we have shown that the renormalized current vertex $\Gamma_{\alpha\beta} = ev\mathcal{D}_{\alpha\beta}$, i.e., the tilting term $u_{\alpha}\sigma_{0}$ in the bare current vertex has no contribution to the AHE and the main effect of the tilting is to produce an anisotropy of the Fermi surface. We have also worked out the \mathcal{I} matrix and \mathcal{D} matrix for the tilted Weyl metals in the previous work [24], so we will just apply the results of such matrices for the study in this work.

Denoting the integrand of $\mathcal{I}_{\alpha\beta}$ in the dc limit as $I_{\alpha\beta}(\mathbf{p}) = \frac{1}{2} \text{Tr}[\sigma_{\alpha} G^{R}(\epsilon, \mathbf{p})\sigma_{\beta} G^{A}(\epsilon, \mathbf{p})]$, one gets $G^{A}\hat{\Gamma}_{\alpha} G^{R} = \Gamma_{\alpha\beta}I_{\beta\gamma}\sigma_{\gamma}$, $G^{R}\hat{\Gamma}_{\alpha}G^{A} = \sigma_{\gamma}I_{\gamma\beta}\Gamma_{\alpha\beta}$. The response functions for the X and Ψ diagrams in Figs. 1(b)–1(d) can then be written as

$$\Pi_{\alpha\beta}^{X} = e^{2}\gamma^{2}v^{2}\omega \int \frac{d\epsilon}{2\pi i} \frac{dn_{F}(\epsilon)}{d\epsilon} \sum_{\mathbf{p}_{1},...,\mathbf{p}_{4}} \delta(\mathbf{p}_{1} + \mathbf{p}_{2} - \mathbf{p}_{3} - \mathbf{p}_{4})$$

$$\times \mathcal{D}_{\alpha\xi}I_{\xi\mu}(\mathbf{p}_1)F_{\mu\nu}(\mathbf{p}_3,\mathbf{p}_4)I_{\nu\gamma}(\mathbf{p}_2)\mathcal{D}_{\gamma\beta}^T, \qquad (7)$$

$$\Pi^{\Psi}_{\alpha\beta} = e^2 \gamma^2 v^2 \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_F(\epsilon)}{d\epsilon} \sum_{\mathbf{p}_1,\dots,\mathbf{p}_4} \delta(\mathbf{p}_1 + \mathbf{p}_4 - \mathbf{p}_2 - \mathbf{p}_3)$$

$$\times \mathcal{D}_{\alpha\xi}I_{\xi\mu}(\mathbf{p}_1)M_{\mu\nu}(\mathbf{p}_3,\mathbf{p}_4)I_{\nu\gamma}(\mathbf{p}_2)\mathcal{D}_{\gamma\beta}^T, \qquad (8)$$

where we have defined

$$F_{\mu\nu}(\mathbf{p}_3, \mathbf{p}_4) \equiv \operatorname{Tr}[\sigma_{\mu} G^R(\epsilon, \mathbf{p}_3) \sigma_{\nu} G^A(\epsilon, \mathbf{p}_4)], \qquad (9)$$

$$M_{\mu\nu}(\mathbf{p}_{3}, \mathbf{p}_{4}) \equiv \operatorname{Tr}[\sigma_{\mu}\sigma_{\nu}G^{A}(\epsilon, \mathbf{p}_{4})G^{A}(\epsilon, \mathbf{p}_{3}) + \sigma_{\nu}\sigma_{\mu}G^{R}(\epsilon, \mathbf{p}_{3})G^{R}(\epsilon, \mathbf{p}_{4})].$$
(10)

The AHE due to the X and Ψ diagrams corresponds to the antisymmetric part of the response function $\Pi^X_{\alpha\beta}$ and $\Pi^{\Psi}_{\alpha\beta}$. In the following, we study the AHE in tilted Weyl metals due to the two diagrams, respectively.

A. AHE from the X diagram

In this subsection, we study the AHE due to the *X* diagram in tilted Weyl metals. To do this, we first compute the anti-symmetric part of the response function $\Pi_{\alpha\beta}^{X}$ in Eq. (7).

For the matrices \mathcal{D} , I, and F in Eq. (7), the symmetric parts of these matrices are $\mathcal{D}_0 \sim \tau^0$, $I^s \sim \tau$, $F^s \sim \tau^0$, and the antisymmetric parts $\mathcal{D}^a \sim \tau^{-1}$, $I^a \sim \tau^0$, $F^a \sim \tau^0$. In the leading order of $1/\epsilon_F \tau$, the antisymmetric part of $\Pi^X_{\alpha\beta}$ is then

$$\Pi_{\alpha\beta}^{X,a} = e^2 \gamma^2 \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_F(\epsilon)}{d\epsilon} \sum_{\mathbf{p}_1, \mathbf{p}_2, \mathbf{Q}} \mathcal{D}_{0,\alpha\gamma} I_{\gamma\mu}^s(\mathbf{p}_1) \\ \times F_{\mu\nu}^a(\mathbf{p}_1 - \mathbf{Q}, \mathbf{p}_2 + \mathbf{Q}) I_{\nu\eta}^s(\mathbf{p}_2) \mathcal{D}_{0,\eta\beta}^T,$$
(11)

where $\mathbf{Q} \equiv \mathbf{p}_{1} - \mathbf{p}_{3} = \mathbf{p}_{4} - \mathbf{p}_{2}$.

The vertex correction factor \mathcal{D}_0 and \mathcal{D}_0^T on the two ends of $\Pi_{\alpha\beta}^{X,a}$ are constant matrices as a function of u and v, as given in our previous work [24], and when multiplied with the remaining part of the response function, it results in an extra total factor $\tilde{\alpha}^2 \approx 9/4 + \mathcal{O}(u^2/v^2)$ only if the remaining part is an antisymmetric matrix of the linear order of u_i , i = 1, 2, 3, which is the case for both the X and Ψ diagrams. For convenience, we will then drop the \mathcal{D}_0 factor in Eq. (11) in the following calculation and add the vertex correction factor $\tilde{\alpha}^2$ at the end.

Since the symmetric part of the *I* matrix in the dc limit is

$$I_{\alpha\beta}^{s}(\mathbf{p}) \approx \pi \tau^{+} \delta(\epsilon - \boldsymbol{u} \cdot \boldsymbol{p} - vp) \frac{1}{p^{2}} \times p_{\alpha} p_{\beta}, \qquad (12)$$

the integration over the momentum \mathbf{p}_1 and \mathbf{p}_2 is bound to the Fermi surface due to the δ function in I^s .

The antisymmetric part of the *F* matrix for the *X* diagram is $F_{\mu\nu}^a = N_{\mu\nu}(F^a)/D(F)$, where

$$N_{\mu\nu}(F^{a}) = 2iv^{2} \{ \epsilon^{0\mu\nu k} \bigg[(p_{1}p_{2k} - p_{2}p_{1k}) + (p_{1} + p_{2})Q_{k} + \frac{\mathbf{u} \cdot \mathbf{Q}}{v} (p_{1k} + p_{2k}) \bigg] - \epsilon^{\mu\nu lk} (\mathbf{p}_{1} - \mathbf{Q})_{l} (\mathbf{p}_{2} + \mathbf{Q})_{k} \},$$

$$D(F) = \bigg[\epsilon - \mathbf{u} \cdot (\mathbf{p}_{1} - \mathbf{Q}) - v |\mathbf{p}_{1} - \mathbf{Q}| + \frac{i}{2\tau_{3}^{+}} \bigg] \bigg[\epsilon - \mathbf{u} \cdot (\mathbf{p}_{1} - \mathbf{Q}) + v |\mathbf{p}_{1} - \mathbf{Q}| + \frac{i}{2\tau_{3}^{-}} \bigg]$$

$$\times \bigg[\epsilon - \mathbf{u} \cdot (\mathbf{p}_{2} + \mathbf{Q}) - v |\mathbf{p}_{2} + \mathbf{Q}| - \frac{i}{2\tau_{4}^{+}} \bigg] \bigg[\epsilon - \mathbf{u} \cdot (\mathbf{p}_{2} + \mathbf{Q}) + v |\mathbf{p}_{2} + \mathbf{Q}| - \frac{i}{2\tau_{4}^{-}} \bigg],$$
(13)

and $\frac{1}{\tau_i^{\pm}} \equiv \frac{1}{\tau}(1 \pm \delta_i), \delta_i \equiv \frac{\mathbf{p}_i \cdot \mathbf{\Delta}}{p_i}, \mu, \nu = 0, 1, 2, 3, \text{ and } l, k = 1, 2, 3.$ In $N_{\mu\nu}(F^a)$, we have only kept the leading order in $1/\tau$.

We assume **u** in the *z* direction for simplicity and $Q = Q(\sin \alpha \cos \beta, \sin \alpha \sin \beta, \cos \alpha)$. Rotate the *z* axis to the direction of Q by the transformation

$$\begin{pmatrix} \hat{\mathbf{x}}'\\ \hat{\mathbf{y}}'\\ \hat{\mathbf{z}}' \end{pmatrix} = \begin{pmatrix} \cos\alpha\cos\beta & \cos\alpha\sin\beta & -\sin\alpha\\ -\sin\beta & \cos\beta & 0\\ \sin\alpha\cos\beta & \sin\alpha\sin\beta & \cos\alpha \end{pmatrix} \begin{pmatrix} \hat{\mathbf{x}}\\ \hat{\mathbf{y}}\\ \hat{\mathbf{z}} \end{pmatrix}$$

where $(\hat{\mathbf{x}}, \hat{\mathbf{y}}, \hat{\mathbf{z}})$ and $(\mathbf{x}', \mathbf{y}', \mathbf{z}')$ are the bases of the old and new frames, respectively. The coordinates of \mathbf{p}_i , i = 1, 2 in the old and new frames are denoted as (p_{ix}, p_{iy}, p_{iz}) and $(p'_{ix}, p'_{iy}, p'_{iz})$, respectively. Assuming in the rotated frame $\mathbf{p}_i = p (\sin \theta_i \cos \phi_i \cdot \hat{\mathbf{x}'} + \sin \theta_i \sin \phi_i \cdot \hat{\mathbf{y}'} + \cos \theta_i \cdot \hat{\mathbf{z}'})$ for i = 1, 2, we then have $\mathbf{p}_1 \cdot \mathbf{Q} = p_1 Q \cos \theta_1$, $\mathbf{p}_2 \cdot \mathbf{Q} = p_2 Q \cos \theta_2$, $\mathbf{u} \cdot \mathbf{Q} = uQ \cos \alpha$.

The coordinates $p_{i\alpha}$, i = 1, 2 in the old frame may be expressed as

$$p_{i,x} = p_i(\cos\phi_i\sin\theta_i\cos\alpha\cos\beta - \sin\theta_i\sin\phi_i\sin\beta + \cos\theta_i\sin\alpha\cos\beta),$$

$$p_{i,y} = p_i(\cos\phi_i\sin\theta_i\cos\alpha\sin\beta + \sin\theta_i\sin\phi_i\cos\beta + \cos\theta_i\sin\alpha\sin\beta),$$

$$p_{i,z} = p_i(-\sin\theta_i\cos\phi\sin\alpha + \cos\theta_i\cos\alpha).$$
(14)

From the δ function in I^s , one can get $p_i = \frac{\epsilon}{v + u\hat{z}_i}$, i = 1, 2, where

$$\hat{z}_i = p_{iz}/p_i = -\sin\theta_i \cos\phi_i \sin\alpha + \cos\theta_i \cos\alpha.$$
(15)

Applying the δ function in I^s to replace ϵ by \mathbf{p}_1 and \mathbf{p}_2 in D(F), we get

$$\frac{1}{D(F)} = \left[(v^2 - u^2 \cos^2 \alpha) Q^2 - 2v^2 p_1 Q \left(\cos \theta_1 + \frac{u}{v} \cos \alpha \right) - \frac{i}{\tau} (v p_1 + u Q \cos \alpha + v \delta_3 |\mathbf{p}_1 - \mathbf{Q}|) \right]^{-1} \\ \times \left[(v^2 - u^2 \cos^2 \alpha) Q^2 + 2v^2 p_2 Q \left(\cos \theta_2 + \frac{u}{v} \cos \alpha \right) + \frac{i}{\tau} (v p_2 - u Q \cos \alpha + v \delta_4 |\mathbf{p}_2 + \mathbf{Q}|) \right]^{-1}.$$
(16)

The AHE due to the X and Ψ diagram is finite only when **u** is nonzero. In this work, we only compute the AHE in the tilted Weyl metals in the leading order of **u** for simplicity. For this reason, we expand 1/D(F) in terms of u/v and keep only the terms up to the linear order of u. We then get

$$\frac{1}{D(F)} \approx \left[v^{2}Q^{2} - 2v^{2}\boldsymbol{p}_{1} \cdot \boldsymbol{Q} - \frac{i}{\tau}v\boldsymbol{p}_{1} - 2v\boldsymbol{p}_{1}\boldsymbol{u} \cdot \boldsymbol{Q} \right]^{-1} \left[v^{2}Q^{2} + 2v^{2}\boldsymbol{p}_{2} \cdot \boldsymbol{Q} + \frac{i}{\tau}v\boldsymbol{p}_{2} + 2v\boldsymbol{p}_{2}\boldsymbol{u} \cdot \boldsymbol{Q} \right]^{-1} \\
\approx \frac{1 + \frac{u}{v}\hat{z}_{1}}{v^{2}Q^{2} - 2v\epsilon Q(\cos\theta_{1} + \frac{u}{v}\cos\alpha) - \frac{i}{\tau}\epsilon + vuQ^{2}\hat{z}_{1}} \frac{1 + \frac{u}{v}\hat{z}_{2}}{v^{2}Q^{2} + 2v\epsilon Q(\cos\theta_{2} + \frac{u}{v}\cos\alpha) + \frac{i}{\tau}\epsilon + vuQ^{2}\hat{z}_{2}} \\
\approx \left(1 + \frac{u}{v}\hat{z}_{1}\right) \left(1 + \frac{u}{v}\hat{z}_{2}\right) \frac{1}{v^{2}Q^{2} - 2v\epsilon Q\cos\theta_{1} - \frac{i}{\tau}\epsilon} \left(1 - \frac{vuQ^{2}\hat{z}_{1} - 2\epsilon uQ\cos\alpha}{v^{2}Q^{2} - 2v\epsilon Q\cos\theta_{1} - \frac{i}{\tau}\epsilon}\right) \tag{17}$$

$$\times \frac{1}{v^{2}Q^{2} + 2v\epsilon Q\cos\theta_{2} + \frac{i}{\tau}\epsilon} \left(1 - \frac{vuQ^{2}\hat{z}_{2} + 2\epsilon uQ\cos\alpha}{v^{2}Q^{2} + 2v\epsilon Q\cos\theta_{2} + \frac{i}{\tau}\epsilon}\right),$$

where we have neglected the linear order of u terms $\sim iuQ \cos \alpha/\tau$ and $i\delta_3/\tau$, $i\delta_4/\tau$ since they contain an extra small factor $1/\tau$.

Putting I^s and F^a together and neglecting the vertex correction at the two ends of the X diagram at the moment, we get the antisymmetric part of the response function Π_{xy}^X as

$$\Pi_{\alpha\beta}^{X,a} = \pi^2 e^2 \gamma^2 \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_F(\epsilon)}{d\epsilon} \int_0^\infty \frac{dp_1}{8\pi^3} p_1^2 \int_0^\infty \frac{dp_2}{8\pi^3} p_2^2 \int_0^\infty \frac{dQ}{8\pi^3} Q^2 \int_0^\pi \sin\theta_1 d\theta_1 \int_0^\pi \sin\theta_2 d\theta_2 \int_0^\pi \sin\alpha d\alpha \\ \times \int_0^{2\pi} d\phi_1 \int_0^{2\pi} d\phi_2 \int_0^{2\pi} d\beta \frac{4iv^2 p_{1\alpha} p_{2\beta} (p_1 + p_2) (p_1 \times p_2) \cdot Q}{p_1^2 p_2^2 D(F)} \prod_{i=1,2} \tau_i^+ \delta(\epsilon - \boldsymbol{u} \cdot \boldsymbol{p}_i - v p_i).$$
(18)

The scalar factor $(\mathbf{p}_1 \times \mathbf{p}_2) \cdot \mathbf{Q} = p_1 p_2 \mathbf{Q} \sin \theta_1 \sin \theta_2 \sin(\phi_2 - \phi_1)$ in the rotated frame, and $\tau_i^+ = \tau/(1 - \frac{u}{v}\hat{z}_i)$, i = 1, 2. For the integrand in Eq. (18), only the factor $p_{1\alpha}p_{2\beta}$ includes the angle β and one can easily integrate out this angle. For \mathbf{u} in the *z* direction, if the electric field \mathbf{E} is also in the *z* direction, $\Pi_{\alpha z}^{X,a} = 0$ after the integration over the angle β for $\alpha \neq z$. For this reason, we only need to consider the case when \mathbf{E} is perpendicular to \mathbf{u} . Assuming the electric field \mathbf{E} in the *y* direction, $\Pi_{zy}^{X,a}$ is zero with the integration over β . We then only need to compute the nonvanishing component $\Pi_{xy}^{X,a}$.

Since

$$\int_0^{2\pi} d\beta p_{1x} p_{2y} = \pi p_1 p_2 [\cos\alpha \sin\theta_1 \sin\theta_2 \sin(\phi_2 - \phi_1) + \sin\alpha (\cos\theta_1 \sin\theta_2 \sin\phi_2 - \cos\theta_2 \sin\theta_1 \sin\phi_1)], \quad (19)$$

the response function $\Pi_{xy}^{X,a}$ for the X diagram becomes

$$\Pi_{xy}^{X,a} = e^2 v^2 \gamma^2 \tau^2 \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_F(\epsilon)}{d\epsilon} \frac{1}{(2\pi)^9} 4iv^2 \pi^3 \int_0^\infty Q^2 dQ \int_0^\pi \sin\alpha d\alpha \int_0^\pi \sin\theta_1 d\theta_1 \int_0^\pi \sin\theta_2 d\theta_2 \int_0^{2\pi} d\phi_1 \int_0^{2\pi} d\phi_1 \int_0^{2\pi} d\phi_2 Q \sin\theta_1 \sin\theta_2 \sin(\phi_2 - \phi_1) [\cos\alpha \sin\theta_1 \sin\theta_2 \sin(\phi_2 - \phi_1) + \sin\alpha(\cos\theta_1 \sin\theta_2 \sin\phi_2 - \cos\theta_2 \sin\theta_1 \sin\phi_1)] \\ \times \frac{v}{v - u\hat{z}_1} \frac{v}{v - u\hat{z}_2} \left(\frac{\epsilon}{v + u\hat{z}_1} + \frac{\epsilon}{v + u\hat{z}_2}\right) \frac{\epsilon^2}{(v + u\hat{z}_1)^3} \frac{\epsilon^2}{(v + u\hat{z}_2)^3} \frac{1}{D(F)}.$$
(20)

It is easy to check that at u = 0, the response function in Eq. (20) vanishes. Expanding Eq. (20) to the linear order of u and combining 1/D(F) in Eq. (17), we get

$$\Pi_{xy}^{X,a}(u) = e^2 v^2 \gamma^2 \tau^2 \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_F(\epsilon)}{d\epsilon} \times 4iv^2 \pi^3 \frac{1}{(2\pi)^9} \times \frac{\epsilon^5}{v^7} \int_0^\infty Q^2 dQ \int_0^\pi \sin \alpha d\alpha \int_0^\pi \sin \theta_1 d\theta_1 \int_0^\pi \sin \theta_2 d\theta_2 \int_0^{2\pi} d\phi_1 \int_0^{2\pi} d\phi_1 \int_0^{2\pi} d\phi_2 \times Q \sin \theta_1 \sin \theta_2 \sin(\phi_2 - \phi_1) |\cos \alpha \sin \theta_1 \sin \theta_2 \sin(\phi_2 - \phi_1) + \sin \alpha (\cos \theta_1 \sin \theta_2 \sin \phi_2 - \cos \theta_2 \sin \theta_1 \sin \phi_1)|$$

$$\times \frac{1}{v^2 Q^2 - 2v\epsilon Q \cos \theta_1 - \frac{i}{\tau} \epsilon} \frac{1}{v^2 Q^2 + 2v\epsilon Q \cos \theta_2 + \frac{i}{\tau} \epsilon} \left[-3 \frac{u}{v} (\hat{z}_1 + \hat{z}_2) - 2 \frac{v u Q^2 \hat{z}_1 - 2\epsilon u Q \cos \alpha}{v^2 Q^2 - 2v\epsilon Q \cos \theta_1 - \frac{i}{\tau} \epsilon} \right].$$
(21)

The angular integration over ϕ_1 , ϕ_2 , and α can be easily done in the above equation and the contributions from the terms with the factor \hat{z}_1 and \hat{z}_2 vanish after this angular integration. The response function for the *X* diagram after the integration over ϕ_1 , ϕ_2 , α , and ϵ becomes

$$\Pi_{xy}^{X,a}(u) = -\frac{\omega}{12\pi^3} e^2 v^3 \epsilon_F^2 u \times \int_0^\infty Q^4 dQ \int_0^\pi \sin\theta_1 d\theta_1 \int_0^\pi \sin\theta_2 d\theta_2 \sin^2\theta_1 \sin^2\theta_2 \frac{1}{v^2 Q^2 - 2v\epsilon_F Q \cos\theta_1 - \frac{i}{\tau}\epsilon_F} \\ \times \left[\frac{1}{v^2 Q^2 - 2v\epsilon_F Q \cos\theta_1 - \frac{i}{\tau}\epsilon_F} - \frac{1}{v^2 Q^2 + 2v\epsilon_F Q \cos\theta_2 + \frac{i}{\tau}\epsilon_F}\right] \frac{1}{v^2 Q^2 + 2v\epsilon_F Q \cos\theta_2 + \frac{i}{\tau}\epsilon_F}$$
(22)
$$= -i\omega \frac{u}{6\pi^3} e^2 v^3 \epsilon_F^2 \times \operatorname{Im} \int_0^\infty dQ S^X(Q),$$

where

$$S^{X}(Q) \equiv Q^{4} \int_{0}^{\pi} \sin\theta_{1} d\theta_{1} \int_{0}^{\pi} \sin\theta_{2} d\theta_{2} \sin^{2}\theta_{1} \sin^{2}\theta_{2} \times \frac{1}{\left(v^{2}Q^{2} + 2v\epsilon_{F}Q\cos\theta_{1} - \frac{i}{\tau}\epsilon_{F}\right)^{2}} \times \frac{1}{v^{2}Q^{2} + 2v\epsilon_{F}Q\cos\theta_{2} + \frac{i}{\tau}\epsilon_{F}}.$$

$$(23)$$

The anomalous Hall conductivity from the *X* diagram is $\sigma_{xy}^X = \prod_{xy}^{X,a}/i\omega$, which is then completely real and dissipationless. The integration in Eq. (22) can be done by a change of variable $x = \cos \theta_1$, $y = \cos \theta_2$, as shown in the Appendix. We get in the leading order of $1/\tau$

$$I^{X} \equiv \operatorname{Im} \int_{0}^{\infty} dQ \, S^{X}(Q) \approx \frac{\pi}{\epsilon_{F} v^{5}}.$$
 (24)

The leading order response function without vertex correction for the *X* diagram from a single valley is

$$\Pi_{xy}^{X,a}(u) \approx -i\omega \frac{e^2 \epsilon_F u}{6\pi^2 v^2}.$$
(25)

The vertex correction adds a factor of 9/4 in the leading order of u/v to the response function $\prod_{xy}^{X}(u)$. For tilted Weyl metals with two valleys, the response function doubles. We then obtain the leading order anomalous Hall conductivity of

the tilted Weyl metals due to the X diagram as

$$\sigma_{xy}^X \approx -\frac{3e^2\epsilon_F u}{4\pi^2 v^2},\tag{26}$$

which is of the same order of the leading order contribution from the NCA diagram $\sigma_{xy}^{NCA} = \frac{4e^2\epsilon_F u}{3\pi^2 v^2}$, but with opposite sign.

B. AHE from the Ψ diagram

In this subsection, we study the AHE in tilted Weyl metals due to the Ψ diagram. To do this, we compute the antisymmetric part of the response function $\Pi^{\Psi}_{\alpha\beta}$ in Eq. (8).

For the matrices \mathcal{D} , I, and M in Eq. (8), the symmetric parts of these matrices are $\mathcal{D}_0 \sim \tau^0$, $I^s \sim \tau$, $M^s \sim \tau^0$, and the antisymmetric parts are $\mathcal{D}^a \sim \tau^{-1}$, $I^a \sim \tau^0$, $M^a \sim \tau^0$. In the leading order of $1/\epsilon_F \tau$, the antisymmetric part of $\Pi^{\Psi}_{\alpha\beta}$ is then

$$\Pi^{\Psi,a}_{\alpha\beta} = e^2 \gamma^2 \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_F(\epsilon)}{d\epsilon} \sum_{\mathbf{p}_1, \mathbf{p}_2, \mathbf{Q}} \mathcal{D}_{0,\alpha\gamma} I^s_{\gamma\mu}(\mathbf{p}_1) M^a_{\mu\nu}(\mathbf{Q} - \mathbf{p}_2, \mathbf{Q} - \mathbf{p}_1) I^s_{\nu\eta}(\mathbf{p}_2) \mathcal{D}^T_{0,\eta\beta}, \tag{27}$$

where $\mathbf{Q} \equiv \mathbf{p}_1 + \mathbf{p}_4 = \mathbf{p}_2 + \mathbf{p}_3$, I^s is given in Eq. (12) and $M^a_{\mu\nu}$ is the antisymmetric part of

$$M_{\mu\nu} \equiv \operatorname{Tr}[\sigma_{\mu}\sigma_{\nu}G^{A}(\mathbf{p}_{4})G^{A}(\mathbf{p}_{3})] + \operatorname{Tr}[\sigma_{\nu}\sigma_{\mu}G^{R}(\mathbf{p}_{3})G^{R}(\mathbf{p}_{4})].$$
(28)

We denote the $G^A G^A$ term in Eq. (28) as M^A and the $G^R G^R$ term as M^R . Since $M^R = (M^A)^*$, the M matrix is then M =2Re M^A. The antisymmetric part of the M^A matrix in the leading order of $1/\tau$ is $M^{A,a}_{\mu\nu} = N_{\mu\nu}(M^{A,a})/D(M^A)$, where

$$N_{\mu\nu}(M^{A,a}) = 2iv\epsilon^{0\mu\nuk} \{ [2(\epsilon - u \cdot Q) + u \cdot (p_1 + p_2)]Q_k - [\epsilon - u \cdot (Q - p_2)]p_{1k} - [\epsilon - u \cdot (Q - p_1)]p_{2k} \} - 2v^2 [(Q - p_1)_{\mu}(Q - p_2)_{\nu} - (Q - p_1)_{\nu}(Q - p_2)_{\mu}],$$

$$D(M^A) = \left[\epsilon - u \cdot (Q - p_1) - v|Q - p_1| - \frac{i}{2\tau_4^+} \right] \left[\epsilon - u \cdot (Q - p_1) + v|Q - p_1| - \frac{i}{2\tau_4^-} \right] \times \left[\epsilon - u \cdot (Q - p_2) - v|Q - p_2| - \frac{i}{2\tau_3^+} \right] \left[\epsilon - u \cdot (Q - p_2) + v|Q - p_2| - \frac{i}{2\tau_3^-} \right].$$
(29)

In the above equation, $\frac{1}{\tau_i^{\pm}} = \frac{1}{\tau}(1 \pm \delta_i)$, $\delta_i = \frac{\mathbf{p}_i \cdot \mathbf{\Delta}}{p_i}$ as defined before. For **u** in the *z* direction and $\mathbf{Q} = Q(\sin \alpha \cos \beta, \sin \alpha \sin \beta, \cos \alpha)$, after the same rotation of the *z* axis to the direction of **Q** as for the X diagram, and applying the δ function in I^s , we obtain

$$D(M^{A}) \approx \left[v^{2}Q^{2} - 2v^{2}\mathbf{p}_{1} \cdot \mathbf{Q} + \frac{i}{\tau}vp_{1} - 2vp_{1}\boldsymbol{u} \cdot (2\boldsymbol{p}_{1} - \boldsymbol{Q}) \right] \left[v^{2}Q^{2} - 2v^{2}\mathbf{p}_{2} \cdot \mathbf{Q} + \frac{i}{\tau}vp_{2} - 2vp_{2}\boldsymbol{u} \cdot (2\boldsymbol{p}_{2} - \boldsymbol{Q}) \right], \quad (31)$$

where we have neglected the second-order **u** terms as well as the \mathbf{u}/τ terms.

Putting I^s and M^a together and neglecting the vertex correction at the two ends of the Ψ diagram at the moment, we get the antisymmetric part of the response function for the Ψ diagram as

$$\Pi_{\alpha\beta}^{\Psi,a} = \pi^{2} e^{2} \gamma^{2} \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_{F}(\epsilon)}{d\epsilon} \times \sum_{\mathbf{p}_{1},\mathbf{p}_{2},\mathbf{Q}} \left[\frac{2iv\epsilon^{0\mu\nu k} p_{1,\alpha} p_{1,\mu} p_{2,\nu} p_{2,\beta} [2(\epsilon - \boldsymbol{u} \cdot \boldsymbol{Q}) + \boldsymbol{u} \cdot (\boldsymbol{p}_{1} + \boldsymbol{p}_{2})] Q_{k}}{p_{1}^{2} p_{2}^{2} \operatorname{D}(\mathcal{M}^{A})} + c.c \right]_{i=1,2} \tau_{i}^{+} \delta(\epsilon - \boldsymbol{u} \cdot \boldsymbol{p}_{i} - \upsilon p_{i}) = e^{2} v^{2} \gamma^{2} \omega \int \frac{d\epsilon}{2\pi i} \frac{dn_{F}(\epsilon)}{d\epsilon} \times 2iv\pi^{2} \frac{1}{(2\pi)^{9}} \int_{0}^{\infty} Q^{2} dQ \int_{0}^{\pi} \sin \alpha d\alpha \int_{0}^{2\pi} d\beta p_{1\alpha} p_{2\beta} \times \int_{0}^{\infty} dp_{1} \int_{0}^{\infty} dp_{2} \int_{0}^{\pi} \sin \theta_{1} d\theta_{1} \int_{0}^{\pi} \sin \theta_{2} d\theta_{2} \int_{0}^{2\pi} d\phi_{1} \int_{0}^{2\pi} d\phi_{2} \tau_{1}^{+} \tau_{2}^{+}(\boldsymbol{p}_{1} \times \boldsymbol{p}_{2}) \cdot \boldsymbol{Q} \times [2\epsilon + \mathbf{u} \cdot (\boldsymbol{p}_{1} + \boldsymbol{p}_{2} - 2\boldsymbol{Q})] \left[\frac{1}{D(M^{A})} - c.c \right] \delta(\epsilon - \upsilon p_{1} - \boldsymbol{u} \cdot \boldsymbol{p}_{1}) \delta(\epsilon - \upsilon p_{2} - \boldsymbol{u} \cdot \boldsymbol{p}_{2}).$$
(32)

At $\mathbf{u} = 0$, the response function $\Pi_{\alpha\beta}^{\Psi,a}$ vanishes. We then expand $\Pi_{\alpha\beta}^{\Psi,a}$ to the linear order of \mathbf{u} and neglect the higher-order contributions. Similar to the *X* diagram, for \mathbf{u} in the *z* direction and \mathbf{E} in the *y* direction, $\Pi_{zy}^{\Psi,a} = 0$ and we only need to consider $\Pi_{xy}^{\Psi,a}$ for the AHE. Keeping only the linear order of u and integrating out the angle β , we get

$$\Pi_{xy}^{\Psi,a}(u) = e^{2}v^{2}\gamma^{2}\tau^{2}\omega \int \frac{d\epsilon}{2\pi i} \frac{dn_{F}(\epsilon)}{d\epsilon} 4iv\pi^{3} \frac{1}{(2\pi)^{9}} \frac{\epsilon^{5}}{v^{6}} \int_{0}^{\infty} Q^{2}dQ \int_{0}^{\pi} \sin\alpha d\alpha \int_{0}^{\pi} \sin\theta_{1}d\theta_{1} \int_{0}^{\pi} \sin\theta_{2}d\theta_{2} \int_{0}^{2\pi} d\phi_{1} \int_{0}^{2\pi} d\phi_{2} \\ \times Q \sin\theta_{1} \sin\theta_{2} \sin(\phi_{2} - \phi_{1}) [\cos\alpha \sin\theta_{1} \sin\theta_{2} \sin(\phi_{2} - \phi_{1}) + \sin\alpha(\cos\theta_{1} \sin\theta_{2} \sin\phi_{2} - \cos\theta_{2} \sin\theta_{1} \sin\phi_{1})] \\ \times \left\{ \frac{1}{v^{2}Q^{2} - 2v\epsilon Q \cos\theta_{1} + \frac{i}{\tau}\epsilon} \frac{1}{v^{2}Q^{2} - 2v\epsilon Q \cos\theta_{2} + \frac{i}{\tau}\epsilon} \left[-\frac{u}{\epsilon}Q \cos\alpha + \frac{u}{2v}(\hat{z}_{1} + \hat{z}_{2}) \right] \right\} \\ - \frac{2uv\hat{z}_{1}(Q^{2} - \frac{\epsilon}{v}Q \cos\theta_{1} - 2\frac{\epsilon^{2}}{v^{2}}) + 2\epsilon uQ \cos\alpha}{v^{2}Q^{2} - 2\epsilon vQ \cos\theta_{1} + \frac{i}{\tau}\epsilon} - \frac{2uv\hat{z}_{2}(Q^{2} - \frac{\epsilon}{v}Q \cos\theta_{2} - 2\frac{\epsilon^{2}}{v^{2}}) + 2\epsilon uQ \cos\alpha}{v^{2}Q^{2} - 2\epsilon vQ \cos\theta_{1} + \frac{i}{\tau}\epsilon} \right] - c.c. \left\}.$$
(33)

After the integration over ϕ_1, ϕ_2 , and α , we get the antisymmetric part of Π_{xy}^{Ψ} as

$$\Pi_{xy}^{\Psi,a}(u) = -\frac{\omega}{12\pi^3} e^2 v^3 \epsilon_F^2 u \int_0^\infty Q^4 dQ \int_0^\pi \sin\theta_1 d\theta_1 \int_0^\pi \sin\theta_2 d\theta_2 \sin^2\theta_1 \sin^2\theta_2 \times \frac{1}{2} \left\{ \frac{1}{v^2 Q^2 - 2v \epsilon_F Q \cos\theta_1 + \frac{i}{\tau} \epsilon_F} \frac{1}{v^2 Q^2 - 2v \epsilon_F Q \cos\theta_2 + \frac{i}{\tau} \epsilon_F} \right. \\\times \left[-\frac{1}{2\epsilon_F^2} - \left(\frac{1}{v^2 Q^2 - 2\epsilon_F v Q \cos\theta_1 + \frac{i}{\tau} \epsilon_F} + \frac{1}{v^2 Q^2 - 2\epsilon_F v Q \cos\theta_2 + \frac{i}{\tau} \epsilon_F} \right) \right] - \text{c.c.} \right\} \\= -i\omega \frac{u}{6\pi^3} e^2 v^3 \epsilon_F^2 \, \text{Im} \int_0^\infty dQ S^\Psi(Q),$$
(34)

for which we separate $S^{\Psi}(Q)$ to two parts as

$$S^{\Psi}(Q) = S^{\Psi,1}(Q) + S^{\Psi,2}(Q),$$

$$S^{\Psi,1}(Q) = -\frac{Q^4}{4\epsilon_F^2} \int_0^{\pi} \sin^3 \theta_1 d\theta_1 \int_0^{\pi} \sin^3 \theta_2 d\theta_2 \frac{1}{v^2 Q^2 - 2v\epsilon_F Q \cos \theta_1 + \frac{i}{\tau} \epsilon_F} \frac{1}{v^2 Q^2 - 2v\epsilon_F Q \cos \theta_2 + \frac{i}{\tau} \epsilon_F},$$

$$S^{\Psi,2}(Q) = -Q^4 \int_0^{\pi} \sin^3 \theta_1 d\theta_1 \int_0^{\pi} \sin^3 \theta_2 d\theta_2 \frac{1}{(v^2 Q^2 - 2v\epsilon_F Q \cos \theta_1 + \frac{i}{\tau} \epsilon_F)^2} \frac{1}{v^2 Q^2 - 2v\epsilon_F Q \cos \theta_2 + \frac{i}{\tau} \epsilon_F}.$$
(35)
(36)

As shown in the Appendix, in the leading order of $1/\tau$, the integration over $S^{\Psi,1}(Q)$ and $S^{\Psi,2}(Q)$ gives

$$I^{\Psi,1} \equiv \text{Im} \int_0^\infty dQ \, S^{\Psi,1}(Q) \approx \frac{17 + 16 \ln 2}{105} \frac{\pi}{\epsilon_F v^5} \qquad (37)$$

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and

$$I^{\Psi,2} \equiv \text{Im} \int_0^\infty dQ \, S^{\Psi,2}(Q) \approx \frac{1+8\ln 2}{15} \frac{\pi}{\epsilon_F v^5}.$$
 (38)

The antisymmetric part of the response function for the Ψ diagram for a single valley without vertex correction is

$$\Pi_{xy}^{\Psi,a}(u) = \Pi_{xy}^{\Psi,1,a}(u) + \Pi_{xy}^{\Psi,2,a}(u) \approx -\frac{4+12\ln 2}{105}i\omega\frac{e^2\epsilon_F u}{\pi^2 v^2}.$$
(39)

Adding the vertex correction factor 9/4 in the leading order of u, and taking into account the two valleys of the tilted Weyl metals, we get the total anomalous Hall conductivity due to the Ψ diagram in the leading order of u as

$$\sigma_{xy}^{\Psi} \approx -\frac{6 + 18\ln 2}{35} \frac{e^2 \epsilon_F u}{\pi^2 v^2} \approx -0.53 \frac{e^2 \epsilon_F u}{\pi^2 v^2}.$$
 (40)

The contribution from the Ψ diagram is also of the same order of the contribution from the NCA diagram $\sigma_{xy}^{NCA} = \frac{4e^2\epsilon_F u}{3\pi^2 v^2}$, but with the opposite sign. This is different from the 2D massive Dirac model, for which the anomalous Hall conductivity from the Ψ diagram vanishes for Gaussian disorder [12].

C. Comparison between the crossed and noncrossing diagrams

The total contribution of the *X* and Ψ diagrams to the AHE for the tilted Weyl metals with two valleys is

$$\sigma_{xy}^{X+\Psi} = \sigma_{xy}^X + \sigma_{xy}^\Psi \approx -1.28 \frac{e^2 \epsilon_F u}{\pi^2 v^2}.$$
 (41)

As a comparison, we plot the different contributions to the anomalous Hall conductivity of the tilted Weyl metals due to both the noncrossing and crossed diagrams in Fig. 2. The anomalous Hall conductivity from the noncrossing diagram was obtained in our previous work [24] and includes three different mechanisms: intrinsic, side jump, and skew scattering. The total anomalous Hall conductivity from the noncrossing diagram for Gaussian disorder in the leading order of u/v is

$$\sigma_{xy}^{\text{NCA}} \approx \frac{4e^2 \epsilon_F u}{3\pi^2 v^2}.$$
(42)

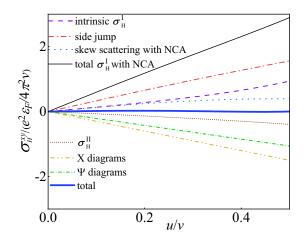


FIG. 2. The different contributions to anomalous Hall conductivity from the noncrossing and crossed diagrams for the 3D tilted Weyl metals with Gaussian disorder as a function of the tilting velocity urescaled by v. The Fermi surface contributions from the noncrossing diagram in the plot come from Ref. [24] and are exact, whereas the results for the crossed diagrams are kept in the linear order of u/v. The intrinsic contribution from the Fermi sea σ_H^{II} comes from Ref. [21]. The black solid line represents the total Fermi surface contribution from the noncrossing diagram, and the blue solid line represents the total contribution from both the Fermi surface and Fermi sea, including both noncrossing and crossed diagrams.

This contribution includes the intrinsic part $\sigma_{int}^{I} = \frac{e^2 \epsilon_F u}{3\pi^2 v^2}$ from the Fermi surface and $\sigma_{int}^{II} = -\frac{e^2 \epsilon_F u}{6\pi^2 v^2}$ from the Fermi sea. The remaining part is the extrinsic contribution due to impurity scatterings, including the side jump and skew scattering contribution as shown in Fig. 2.

From Eqs. (41) and (42), we see that the inclusion of the X and Ψ diagrams cancels most of the contribution from the noncrossing diagram in the leading order of u/v, as shown in Fig. 2. This is similar to the case of the 2D massive Dirac model at large energy with Gaussian disorder. However, for the 2D massive Dirac model, the inclusion of the X and Ψ diagram changes the dependence of the total anomalous Hall conductivity on the energy from $\sigma_{xy}^{\text{NCA}} \sim m/\epsilon_F$ to $\sigma_{xy}^{\text{total}} \sim (m/\epsilon_F)^3$, which greatly reduces the total anomalous Hall conductivity in the metallic regime $m/\epsilon_F \ll 1$. In contrast, for tilted Weyl metals, the contributions of the X and Ψ diagrams have the same dependence on the Fermi energy as the noncrossing diagram and the cancellation is due to the opposite signs but close values of the coefficients of the two contributions.

III. DISCUSSION

The expansion of the response functions of the X and Ψ diagrams to the second order of **u** reveals that the contributions to the AHE from these diagrams vanish in the second order of **u** for the tilted Weyl metals. The next leading-order corrections to the AHE from the X and Ψ diagrams are then $\sim (u/v)^3$. The same is true for the contribution to the AHE from the noncrossing diagram [24]. For the type-I Weyl metals with not very large u/v, the anomalous Hall conductivity in the linear order of u we obtained in this work is then accurate enough.

The contributions to the AHE from the X and Ψ diagrams do not depend on the disorder strength and scattering rate for Gaussian disorder, and have the same dependence on the Fermi energy and the tilting of the Weyl metals as the NCA diagram in the leading order. This makes it hard to distinguish the contributions from the two types of diagrams in experiments. However, the skew scattering contribution comes from the consecutive electron scatterings off two closely located impurities with distance of the order of electron Fermi wavelength [9-12]. The impurity density required to observe the AHE due to the X and Ψ diagrams as well as the skew scattering contribution in the NCA diagram is then much higher than that to observe the side jump effects originating from incoherent single impurity scatterings. The self-average of the impurities in the diagrammatic technique indicates an average over all the independent and equivalent subsystems of the size of the phase coherence length l_{ϕ} . To validate the self-average over the impurities in the calculation of the skew scattering contribution, every independent subsystem of the size of the phase coherence length l_{ϕ} (which is much smaller than the sample size) needs to contain at least one pair of such closely located impurities. We can then estimate the minimum impurity density required in the system to observe the effects of the X and Ψ diagrams as follows. Assume there are N randomly distributed impurities in each independent subsystem of the size of l_{ϕ} . The probability for two randomly

chosen impurities in this subsystem to have a distance less than or equal to the Fermi wavelength λ_F is $\sim (\lambda_F/l_{\phi})^3$. Since there are N(N-1)/2 ways to choose a pair of impurities in the subsystem, the total pair number of the rare impurity complexes in the subsystem is $\sim \frac{N(N-1)}{2} (\lambda_F / l_{\phi})^3$. This pair number needs to be greater than one to validate the results of the skew scattering contribution, including the X and Ψ diagrams and the noncrossing skew scattering diagrams in Refs. [5,24], so we get $N > \sqrt{2}(l_{\phi}/\lambda_F)^{3/2}$ and the impurity density $n_{\rm imp}^{sk} > \sqrt{2}/(\lambda_F l_{\phi})^{3/2}$. (Note that under this impurity density, the condition $k_F l \gg 1$ can still be satisfied.) As a comparison, the impurity density required to observe the incoherent single impurity scattering effect, e.g., the side jump contribution, is $n_{imp}^{sj} > 1/(l_{\phi})^3$. Since $l_{\phi} > l \gg \lambda_F$, the minimum impurity density to observe the AHE due to skew scatterings is much higher than that of observing the side jump contribution. The same is true for the 2D massive Dirac systems for which $n_{imp}^{sj} > 1/(l_{\phi})^2$ and $n_{imp}^{sk} > \sqrt{2}/(\lambda_F l_{\phi})$.

For the recently studied type-I Weyl metal Co₃Sn₂S₂ in experiments [25,26], the topological Chern-Simons term [20,24,28] gives an extra anomalous Hall conductivity $\sigma_H \sim$ $\frac{e^2}{2\pi^2}\mathcal{K}$ which is proportional to the distance \mathcal{K} between the two Weyl nodes. This contribution is independent of the impurity scatterings and constitutes part of the intrinsic AHE. For Co₃Sn₂S₂, the AHE from the Chern-Simons term is one order of magnitude greater than both the contribution from the noncrossing diagram and the crossed diagrams of the lowenergy effective Hamiltonian with Gaussian disorder [23] so it dominates the total AHE in this system. This makes it hard to distinguish the contribution of the disorder in experiments, either due to the NCA diagram or the crossed diagrams. In Ref. [25], all the AHE measured in Co₃Sn₂S₂ was attributed to the intrinsic one. In Ref. [26], the authors measured the AHE in both the clean and dirty samples, but the difference of the anomalous Hall conductivity in the two samples is only about 10% of the clean case. To better observe the effects of the disorder and the interplay of the noncrossing and crossed diagrams in experiments, one may increase the Fermi level of $Co_3Sn_2S_2$ by doping to enhance the weight of the contribution to the AHE due to both the noncrossing and crossed diagrams since the anomalous Hall conductivity from the Chern-Simons term does not depend on the Fermi energy.

Another way to observe the disorder effects and the interplay between the crossed diagrams and the noncrossing diagram in $Co_3Sn_2S_2$ is by the measurement of the anomalous Nernst effect (ANE) [26,29–31] in such a system. The ANE only comes from the scatterings on the Fermi surface so the Chern-Simons term has no contribution to the ANE. The ANE is proportional to the Fermi surface contribution of the AHE, i.e., σ_H^I , we studied in Ref. [24] and this work, with the ratio $\sim k_B T/\epsilon_F$ [23]. By measuring the ANE in different disorder conditions, one can tell whether and when the skew scatterings play a role in both the ANE and AHE in the system. Indeed, in Ref. [26], the ANEs in the disordered samples are about three to five times that of the clean sample, which makes the effects of the disorder much more discernible in the ANE than in the AHE. The large enhancement of the ANE by the disorder in this experiment agrees qualitatively with our calculation for the NCA diagram in the previous work [24] and seems to indicate that the crossed diagrams do not contribute to the ANE in the measured disordered samples based on our calculation of the Gaussian disorder in this work. One possible reason may be that the impurity densities in the disordered samples in the experiment did not reach the required density n_{imp}^{sk} to observe the skew scattering effects. On the other hand, the real system may also include disorders more complicated than the Gaussian disorder considered in this work [12,17,32–34], which may change the results of the AHE and ANE significantly. For example, it was shown in Ref. [12] that for the 2D massive Dirac model with smooth disorder, the anomalous Hall conductivity is enhanced by the Xand Ψ diagrams instead of being canceled as in the case of Gaussian disorder. Impurities with higher-order correlations than the Gaussian disorder may also introduce a new contribution to the AHE [33]. Besides, the impurities with internal structure may also activate a new skew scattering mechanism and change the AHE significantly [17,34]. A more complete theoretical study including various realistic disorders is then needed to tell whether the crossed diagrams play a role in such experiments. We will leave this for a future study since the study of the 3D tilted Weyl metals with these types of disorder is more complicated than the 2D massive Dirac model due to the increased dimensionality. On the other hand, to observe the AHE or ANE due to the

crossed diagrams, more experiments with a wider range of disorder conditions may also need to be carried out in the future.

IV. SUMMARY

To sum up, we study the AHE due to the crossed X and Ψ diagrams in type-I Weyl metals with Gaussian disorder. We show that similar to the 2D massive Dirac model, the contributions from the crossed diagrams cancel a majority of the contribution from the noncrossing diagram of the lowenergy effective Hamiltonian. However, the impurity density needed to observe the AHE due to the X and Ψ diagrams is much higher than that of observing the contribution of the noncrossing diagrams with single impurity scatterings. We estimate the minimum impurity density to observe the AHE due to the X and Ψ diagrams and discuss the experimental relevance to observe the AHE from such crossed diagrams in the type-I Weyl metal Co₃Sn₂S₂.

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APPENDIX: CALCULATION OF I^X AND I^{Ψ}

In this Appendix, we show the details of the integration in Eqs. (24), (37), and (38) for the X and Ψ diagram. We first present the integration

$$I^{X} = \operatorname{Im} \int_{0}^{\infty} dQ S^{X}(Q)$$

=
$$\operatorname{Im} \int_{0}^{\infty} Q^{4} dQ \int_{0}^{\pi} \sin^{3} \theta_{1} d\theta_{1} \int_{0}^{\pi} \sin^{3} \theta_{2} d\theta_{2} \frac{1}{\left(v^{2} Q^{2} + 2v\epsilon_{F} Q \cos \theta_{1} - \frac{i}{\tau} \epsilon_{F}\right)^{2}} \frac{1}{v^{2} Q^{2} + 2v\epsilon_{F} Q \cos \theta_{2} + \frac{i}{\tau} \epsilon_{F}}$$

By a change of the variable $x = \cos \theta_1$, $y = \cos \theta_2$ and denoting ϵ_F as ϵ for brevity, we get

$$I^{X} = \int_{0}^{\infty} Q^{4} dQ \int_{-1}^{1} dx \int_{-1}^{1} dy (1 - x^{2})(1 - y^{2}) \left\{ -\frac{\frac{\epsilon}{\tau}}{(v^{2}Q^{2} + 2v\epsilon Qy)^{2} + \frac{\epsilon^{2}}{\tau^{2}}} \frac{(v^{2}Q^{2} + 2v\epsilon Qx)^{2} - \frac{\epsilon^{2}}{\tau^{2}}}{[(v^{2}Q^{2} + 2v\epsilon Qx)^{2} + \frac{\epsilon^{2}}{\tau^{2}}]^{2}} + \frac{2\frac{\epsilon}{\tau}(v^{2}Q^{2} + 2v\epsilon Qy)}{(v^{2}Q^{2} + 2v\epsilon Qy)^{2} + \frac{\epsilon^{2}}{\tau^{2}}} \frac{v^{2}Q^{2} + 2v\epsilon Qx}{[(v^{2}Q^{2} + 2v\epsilon Qx)^{2} + \frac{\epsilon^{2}}{\tau^{2}}]^{2}} \right\}.$$
(A1)

We denote the first and second term in the above equation as $I^{X,1}$ and $I^{X,2}$, respectively, and calculate them separately in the following. With the variable substitution $v^2Q^2 + 2v\epsilon Qy = t$, $v^2Q^2 + 2v\epsilon Qx = s$ and the relationship

$$\frac{\frac{\epsilon}{\tau}}{(v^2Q^2 + 2v\epsilon Qy)^2 + \frac{\epsilon^2}{\tau^2}} \approx \pi \delta(v^2Q^2 + 2v\epsilon Qy),\tag{A2}$$

we get

$$I^{X,1} = -\pi \int_{0}^{\infty} \frac{Q^{4}}{(2\epsilon vQ)^{2}} dQ \int_{v^{2}Q^{2}-2v\epsilon Q}^{v^{2}Q^{2}+2v\epsilon Q} ds \left[1 - \left(\frac{s - v^{2}Q^{2}}{2v\epsilon Q}\right)^{2}\right] \frac{s^{2} - \frac{\epsilon^{2}}{\tau^{2}}}{(s^{2} + \frac{\epsilon^{2}}{\tau^{2}})^{2}} \int_{v^{2}Q^{2}-2v\epsilon Q}^{v^{2}Q^{2}+2v\epsilon Q} dt \left[1 - \left(\frac{t - v^{2}Q^{2}}{2v\epsilon Q}\right)^{2}\right] \delta(t), \quad (A3)$$

$$I^{X,2} = \frac{2\epsilon}{\tau} \int_{0}^{\infty} \frac{Q^{4}}{(2\epsilon vQ)^{2}} dQ \int_{v^{2}Q^{2}-2v\epsilon Q}^{v^{2}Q^{2}+2v\epsilon Q} ds \left[1 - \left(\frac{s - v^{2}Q^{2}}{2v\epsilon Q}\right)^{2}\right] \frac{s}{(s^{2} + c^{2})^{2}} \int_{v^{2}Q^{2}-2v\epsilon Q}^{v^{2}Q^{2}+2v\epsilon Q} dt \left[1 - \left(\frac{t - v^{2}Q^{2}}{2v\epsilon Q}\right)^{2}\right] \frac{t}{t^{2} + c^{2}}. \quad (A4)$$

We first do the integration of $I^{X,1}$. The integration over s and t for $I^{X,1}$ in Eq. (A3) can be carried out separately at first. To get a nonvanishing integration over the $\delta(t)$ factor in Eq. (A3), Q must be limited to $0 < Q < 2\epsilon/v$. Denoting $c \equiv \epsilon/\tau$ and integrating out s and t, $I^{X,1}$ becomes

$$I^{X,1} = \int_{0}^{2\epsilon/v} dQ \frac{-\pi Q^{4}}{(2\epsilon vQ)^{2}} \left[1 - \frac{v^{2}Q^{2}}{4\epsilon^{2}} \right] \left\{ -\left(1 - \frac{v^{2}Q^{2}}{4\epsilon^{2}}\right) \frac{s}{s^{2} + c^{2}} + \frac{1}{2\epsilon^{2}} \left[c\pi\delta(s) + \frac{1}{2}\ln(s^{2} + c^{2}) \right] - \frac{1}{4\epsilon^{2}v^{2}Q^{2}} \left[s + cs\delta(s) - 2c\arctan\left(\frac{s}{c}\right) \right] \right\} \Big|_{s=v^{2}Q^{2} - 2v\epsilon Q}^{vQ^{2} + 2v\epsilon Q}.$$
(A5)

Neglecting the small terms in $1/\tau$, we get

$$I^{X,1} = \int_{0}^{2\epsilon/v} dQ \frac{-\pi Q^4}{(2\epsilon vQ)^2} \left[1 - \frac{v^2 Q^2}{4\epsilon^2} \right] \times \left\{ -\left(1 - \frac{v^2 Q^2}{4\epsilon^2}\right) \frac{s}{s^2 + c^2} + \frac{1}{4\epsilon^2} \ln(s^2 + c^2) - \frac{1}{4\epsilon^2 v^2 Q^2} s \right\} \Big|_{s=v^2 Q^2 - 2v\epsilon Q}^{v^2 Q^2 + 2v\epsilon Q} = \frac{\pi}{2\epsilon v^5} \left[1 - \frac{1}{15} (1 + 8\ln 2) \right].$$
(A6)

Similarly, after the integration over *s* and *t*, $I^{X,2}$ becomes

$$I^{X,2} = 2 \int_0^\infty \frac{Q^4}{(2\epsilon vQ)^2} dQ \left[\left(1 - \frac{v^2 Q^2}{4\epsilon^2} \right) \frac{1}{2} \ln(t^2 + c^2) + \frac{1}{2\epsilon^2} t - \frac{1}{8\epsilon^2 v^2 Q^2} t^2 \right] \Big|_{t=v^2 Q^2 - 2v\epsilon Q}^{v^2 Q^2 + 2v\epsilon Q} \times \left[- \left(1 - \frac{v^2 Q^2}{4\epsilon^2} \right) \frac{\pi}{2} \delta(s) + \frac{1}{4\epsilon^2} \arctan\left(\frac{s}{c} \right) \right] \Big|_{s=v^2 Q^2 - 2v\epsilon Q}^{v^2 Q^2 + 2v\epsilon Q},$$
(A7)

where we have omitted the terms proportional to c or $s\delta(s)$. The integration over the terms with $\delta(s)$ in Eq. (A7) is zero because at where we have only control of the properties at $c \in Cr(c)$, the integrand become zero. For this reason, we only need to consider the terms with $\frac{1}{4\epsilon^2} \arctan(\frac{s}{c})$ after the integration of s. Since c is small, $\arctan(\frac{s}{c})|_{s=v^2Q^2-2v\epsilon Q}$ is nonzero only when $v^2Q^2 - 2v\epsilon Q < c$ $0 < v^2 Q^2 + 2v \epsilon Q$, i.e., $0 < Q < 2\epsilon/v$. In this regime,

$$\arctan\left(\frac{s}{c}\right)\Big|_{s=v^2Q^2-2v\epsilon Q}^{v^2Q^2+2v\epsilon Q} \approx \pi$$
(A8)

and

$$I^{X,2} = \frac{\pi}{2\epsilon^2} \int_0^{2\epsilon/\nu} \frac{Q^4}{(2\epsilon\nu Q)^2} dQ \times \left[\frac{1}{2}\left(1 - \frac{\nu^2 Q^2}{4\epsilon^2}\right) \ln\frac{(\nu^2 Q^2 + 2\nu\epsilon Q)^2 + c^2}{(\nu^2 Q^2 - 2\nu\epsilon Q)^2 + c^2} + \frac{\nu Q}{\epsilon}\right]$$
$$= \frac{\pi}{2\epsilon\nu^5} \left[1 + \frac{1}{15}(1 + 8\ln 2)\right].$$

Adding $I^{X,1}$ and $I^{X,2}$ together, we get $I^X = \pi/\epsilon_F v^5$ as in Eq. (24). We next compute $I^{\Psi} \equiv \text{Im} \int_0^\infty dQ S^{\Psi}(Q)$ for the Ψ diagram. As shown in the main text, we divide I^{Ψ} into two parts $I^{\Psi,1}$ and $I^{\Psi,2}$ and compute them separately.

From Eq. (35), we get

$$\begin{split} I^{\Psi,1} &= \operatorname{Im} \int_{0}^{\infty} dQ S^{\Psi,1}(Q) \\ &= \int_{0}^{\infty} \frac{Q^{4}}{4\epsilon^{2}} dQ \int_{-1}^{1} dx \int_{-1}^{1} dy (1-x^{2})(1-y^{2}) \\ &\times \left[\frac{\frac{\epsilon}{\tau}}{(v^{2}Q^{2}-2v\epsilon Qy)^{2}+\frac{\epsilon^{2}}{\tau^{2}}} \frac{(v^{2}Q^{2}-2v\epsilon Qx)}{(v^{2}Q^{2}-2v\epsilon Qx)^{2}+\frac{\epsilon^{2}}{\tau^{2}}} + \frac{\frac{\epsilon}{\tau}}{(v^{2}Q^{2}-2v\epsilon Qx)^{2}+\frac{\epsilon^{2}}{\tau^{2}}} \frac{v^{2}Q^{2}-2v\epsilon Qy}{(v^{2}Q^{2}-2v\epsilon Qy)^{2}+\frac{\epsilon^{2}}{\tau^{2}}} \right] \\ &= \frac{\pi}{2\epsilon^{2}} \int_{0}^{\infty} \frac{Q^{4}}{(2\epsilon vQ)^{2}} dQ \int_{v^{2}Q^{2}-2v\epsilon Q}^{v^{2}Q^{2}+2v\epsilon Q} ds \left[1 - \left(\frac{s-v^{2}Q^{2}}{2v\epsilon Q} \right)^{2} \right] \frac{s}{s^{2}+\frac{\epsilon^{2}}{\tau^{2}}} \int_{v^{2}Q^{2}-2v\epsilon Q}^{v^{2}Q^{2}+2v\epsilon Q} dt \left[1 - \left(\frac{t-v^{2}Q^{2}}{2v\epsilon Q} \right)^{2} \right] \delta(t) \\ &= \frac{\pi}{2\epsilon^{2}} \int_{0}^{2\epsilon/v} dQ \frac{Q^{4}}{(2\epsilon vQ)^{2}} \left(1 - \frac{v^{2}Q^{2}}{4\epsilon^{2}} \right) \left[\left(1 - \frac{v^{2}Q^{2}}{4\epsilon^{2}} \right) \frac{1}{2} \ln \frac{(v^{2}Q^{2}+2v\epsilon Q)^{2}+c^{2}}{(v^{2}Q^{2}-2v\epsilon Q)^{2}+c^{2}} + \frac{vQ}{\epsilon} \right] \\ &= \frac{\pi}{\epsilon v^{5}} \frac{17 + 16\ln 2}{105}. \end{split}$$
(A9)

Similarly, we get

Ì

$$t^{\Psi,2} = -\int_{0}^{\infty} Q^{4} dQ \times \operatorname{Im} \int_{-1}^{1} dx \int_{-1}^{1} dy (1-x^{2})(1-y^{2}) \left[\frac{1}{(v^{2}Q^{2}-2v\epsilon Qx+\frac{i}{\tau}\epsilon)^{2}} \times \frac{1}{v^{2}Q^{2}-2v\epsilon Qy+\frac{i}{\tau}\epsilon} \right]$$

$$= \int_{0}^{\infty} Q^{4} dQ \int_{-1}^{1} dx \int_{-1}^{1} dy (1-x^{2})(1-y^{2}) \times \left[\frac{\frac{\epsilon}{\tau}}{(v^{2}Q^{2}-2v\epsilon Qy)^{2}+\frac{\epsilon^{2}}{\tau^{2}}} \frac{(v^{2}Q^{2}-2v\epsilon Qx)^{2}-\frac{\epsilon^{2}}{\tau^{2}}}{[(v^{2}Q^{2}-2v\epsilon Qx)^{2}+\frac{\epsilon^{2}}{\tau^{2}}]^{2}} + \frac{2\frac{\epsilon}{\tau}(v^{2}Q^{2}-2v\epsilon Qy)}{(v^{2}Q^{2}-2v\epsilon Qy)^{2}+\frac{\epsilon^{2}}{\tau^{2}}} \frac{v^{2}Q^{2}-2v\epsilon Qx}{[(v^{2}Q^{2}-2v\epsilon Qx)^{2}+\frac{\epsilon^{2}}{\tau^{2}}]^{2}} \right]$$

$$= -I^{X,1} + I^{X,2} = \frac{\pi}{\epsilon v^{5}} \frac{1}{15} (1+8\ln 2).$$
(A10)

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